Schottky Barrier Diode

These Schottky barrier diodes are designed for high current, handling capability, and low forward voltage performance.

- Low Forward Voltage 0.35 Volts (Typ) @ $I_F = 10 \text{ mAdc}$
- High Current Capability

Storage Temperature Range



ON Semiconductor®

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HIGH CURRENT SCHOTTKY BARRIER DIODE

1, 2, 5, 6 CATHODE

| MAXIMUM RATINGS (T _J = 125°C unless otherwise noted) | | | | |
|---|----------------|------------|-------------|--|
| Rating | Symbol | Value | Unit | |
| Reverse Voltage | V _R | 23 | V | |
| Forward Power Dissipation @ T _A = 25°C Derate above 25°C | P _F | 200 2.0 | mW mW/°C | |
| Forward Current (DC) Continuous | ١ _F | 1 | А | |
| Forward Current t = 8.3 ms Half Sinewave; JEDEC Method | IF | 7.5 | A | |
| Junction Temperature | Tj | 125 Max | °C | |

-55 to +150

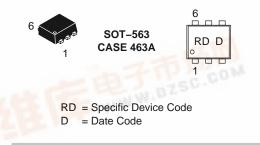
T_{stq}

°C

MARKING DIAGRAM

o 3.4

ANODE



ORDERING INFORMATION

| Device | Package | Shipping | |
|--------------|---------|------------------|--|
| NSR0320XV6T1 | SOT-563 | 3000/Tape & Reel | |

WWW.DZSC.COM

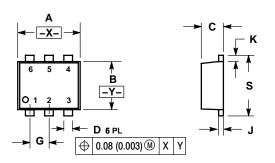


ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|---|----------------|-----|------|------|------|
| Total Capacitance (V _R = 5.0 V, f = 1.0 MHz) | CT | - | 30 | 35 | pF |
| Reverse Leakage (V _R = 15 V) | I _R | - | 10 | 50 | μAdc |
| Forward Voltage (I _F = 10 mAdc) | V _F | - | 0.24 | 0.27 | Vdc |
| Forward Voltage (I _F = 100 mAdc) | V _F | - | 0.30 | 0.35 | Vdc |
| Forward Voltage (I _F = 900 mAdc) | V _F | - | 0.45 | 0.50 | Vdc |

PACKAGE DIMENSIONS

SOT-563, 6 LEAD PLASTIC PACKAGE CASE 463A-01 ISSUE O



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

| | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 1.50 | 1.70 | 0.059 | 0.067 |
| В | 1.10 | 1.30 | 0.043 | 0.051 |
| C | 0.50 | 0.60 | 0.020 | 0.024 |
| D | 0.17 | 0.27 | 0.007 | 0.011 |
| G | 0.50 BSC | | 0.020 BSC | |
| J | 0.08 | 0.18 | 0.003 | 0.007 |
| K | 0.10 | 0.30 | 0.004 | 0.012 |
| S | 1.50 | 1.70 | 0.059 | 0.067 |

| STYLE 1: | STYLE 2: | STYLE 3: | STYLE 4: |
|-------------------------------|-------------------------------|---------------------------------|------------------|
| PIN 1. EMITTER 1 | PIN 1. EMITTER 1 | PIN 1. CATHODE 1 | PIN 1. COLLECTOR |
| 2. BASE 1 | 2. EMITTER2 | 2. CATHODE 1 | 2. COLLECTOR |
| COLLECTOR 2 | 3. BASE 2 | ANODE/ANODE 2 | 3. BASE |
| EMITTER 2 | COLLECTOR 2 | CATHODE 2 | 4. EMITTER |
| 5. BASE 2 | 5. BASE 1 | CATHODE 2 | 5. COLLECTOR |
| COLLECTOR 1 | COLLECTOR 1 | ANODE/ANODE 1 | 6. COLLECTOR |
| | | | |

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